Electronic Supplementary Information

Two-Dimensional Stanane: Strain-Tunable Electronic Structure,

High Carrier Mobility, and Pronounced Light Adsorption

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Fig. S1 The top and side views of chair, boat, and stirrup forms of stanane monolayer with relative cohesive energies. The respective cell parameters (a, b), lengths of Sn-Sn $(l_{\text{Sn-Sn}})$ and Sn-H $(l_{\text{Sn-H}})$ bonds are also given.



Fig. S2 Band structure of stanane computed at PBE+SOC level.



Fig. S3 Band structures of stanane (a) bilayer, (b) trilayer, and (c) four-layer computed at HSE06 level.



Fig. S4 Band structure of stanane monolayer in the rectangle supercell.



Fig. S5 Phonon band structures of stanane with (a) 5% tensile strain and (b) 3% compress strain.



Fig. S6 Total energy-strain relationship of stanane along x (a) and y (b) directions. Δl refers to the dilation along x or y, while l_0 refers to the lattice constant of a or b at equilibrium geometry.



Fig. S7 Shifts of CBM and VBM under uniaxial strain along *x* and *y* directions for stanane.